

## FEATURES

### Low offset voltage (maximum specifications)

B-Grade: 25  $\mu\text{V}$  (SOIC)

A-Grade: 50  $\mu\text{V}$  (SOIC), 90  $\mu\text{V}$  (MSOP)

### Very low offset voltage drift

B-Grade: 0.25  $\mu\text{V}/^\circ\text{C}$  (SOIC)

A-Grade: 0.55  $\mu\text{V}/^\circ\text{C}$  (SOIC) and 1.2  $\mu\text{V}/^\circ\text{C}$  (MSOP), specified over  $-40^\circ\text{C}$  to  $+125^\circ\text{C}$ , MSL1 rated

### Low input bias current: 1.0 nA maximum

### Low noise: 7 nV/ $\sqrt{\text{Hz}}$ typical

### CMRR, PSRR, and $A_{\text{VO}}$ > 120 dB minimum

### Low supply current: 400 $\mu\text{A}$ per amplifier typical

### Wide bandwidth: 4.0 MHz

### Dual-supply operation: $\pm 5\text{ V}$ to $\pm 15\text{ V}$

### Unity-gain stable

### No phase reversal

## APPLICATIONS

### Process control front-end amplifiers

### Wireless base station control circuits

### Optical network control circuits

### Instrumentation

### Sensors and controls: thermocouples, resistor thermal detectors (RTDs), strain bridges, and shunt current measurements

### Precision filters

## GENERAL DESCRIPTION

The **ADA4077-2** is a dual amplifier featuring extremely low offset voltage and drift and low input bias current, noise, and power consumption. Outputs are stable with capacitive loads of more than 1000 pF with no external compensation.

Applications for this amplifier include sensor signal conditioning (such as thermocouples, RTDs, strain gauges), process control front-end amplifiers, and precision diode power measurement in optical and wireless transmission systems. The **ADA4077-2** is useful in line powered and portable instrumentation, precision filters, and voltage or current measurement and level setting.

Unlike the amplifiers of some competitors, the **ADA4077-2** is specified over the extended industrial temperature range for operation from  $-40^\circ\text{C}$  to  $+125^\circ\text{C}$  with MSL1 rating for the most demanding operating environments. It is available in 8-lead SOIC (including the B-Grade) and MSOP (A-Grade only) packages.

## PIN CONNECTION DIAGRAMS

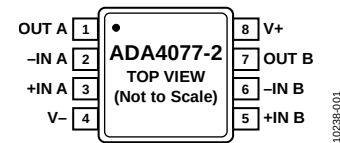


Figure 1. **ADA4077-2** Pin Configuration, 8-Lead MSOP

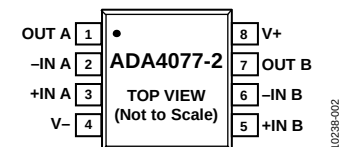


Figure 2. **ADA4077-2** Pin Configuration, 8-Lead SOIC\_N

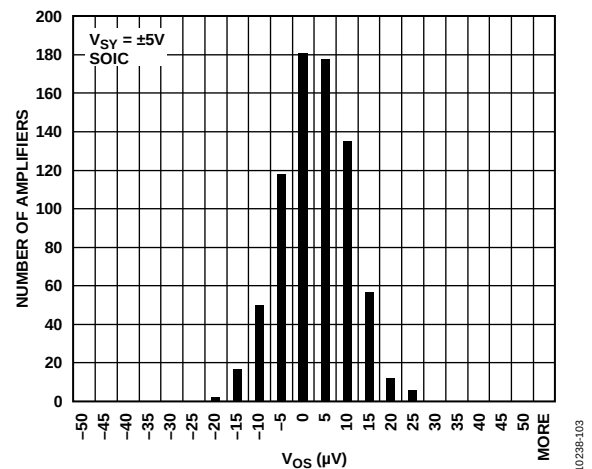


Figure 3. Offset Voltage Distribution

Table 1. Evolution of Precision Devices by Generation

| Op Amp | 1st  | 2nd  | 3rd   | 4th    | 5th    | 6th       |
|--------|------|------|-------|--------|--------|-----------|
| Single | OP07 | OP77 | OP177 | OP1177 | AD8677 |           |
| Dual   |      |      |       | OP2177 |        | ADA4077-2 |
| Quad   |      |      |       | OP4177 |        |           |

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REVISION HISTORY

10/12—Revision 0: Initial Version

## SPECIFICATIONS

ELECTRICAL CHARACTERISTICS,  $\pm 5.0$  V

$V_{SY} = \pm 5.0$  V,  $V_{CM} = 0$  V,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

Table 2.

| Parameter                              | Symbol                   | Test Conditions/Comments                               | Min  | Typ      | Max  | Unit                         |
|----------------------------------------|--------------------------|--------------------------------------------------------|------|----------|------|------------------------------|
| INPUT CHARACTERISTICS                  |                          |                                                        |      |          |      |                              |
| Offset Voltage (B Grade, SOIC)         | $V_{OS}$                 | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$         |      | 10       | 25   | $\mu\text{V}$                |
| Offset Voltage Drift (B Grade, SOIC)   | $\Delta V_{OS}/\Delta T$ | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$         |      | 0.1      | 65   | $\mu\text{V}/^\circ\text{C}$ |
| Offset Voltage (A Grade)               | $V_{OS}$                 | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$         |      |          |      |                              |
| SOIC                                   |                          |                                                        |      | 15       | 50   | $\mu\text{V}$                |
| MSOP                                   |                          |                                                        |      |          | 105  | $\mu\text{V}$                |
|                                        |                          |                                                        |      | 50       | 90   | $\mu\text{V}$                |
| Offset Voltage Drift (A Grade)         | $\Delta V_{OS}/\Delta T$ | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$         |      |          | 220  | $\mu\text{V}$                |
| SOIC                                   |                          |                                                        |      | 0.25     | 0.55 | $\mu\text{V}/^\circ\text{C}$ |
| MSOP                                   |                          |                                                        |      | 0.5      | 1.2  | $\mu\text{V}/^\circ\text{C}$ |
| Input Bias Current                     | $I_B$                    | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$         | -1   | -0.4     | +1   | nA                           |
| Input Offset Current                   | $I_{OS}$                 | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$         | -1.5 |          | +1.5 | nA                           |
|                                        |                          | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$         | -0.5 | +0.1     | +0.5 | nA                           |
|                                        |                          | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$         | -1.0 |          | +1.0 | nA                           |
| Input Voltage Range                    |                          |                                                        | -3.8 |          | +3   | V                            |
| Common-Mode Rejection Ratio            | CMRR                     | $V_{CM} = -3.8$ V to +3V                               | 122  | 140      |      | dB                           |
|                                        |                          | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$         | 120  |          |      | dB                           |
| Large Signal Voltage Gain              | $A_{VO}$                 | $R_L = 2$ k $\Omega$ , $V_O = -3.0$ V to +3.0 V        | 121  | 130      |      | dB                           |
|                                        |                          | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$         | 120  |          |      | dB                           |
| Input Capacitance                      | $C_{INDM}$               | Differential mode                                      |      | 3        |      | pF                           |
|                                        | $C_{INCM}$               | Common mode                                            |      | 5        |      | pF                           |
| Input Resistance                       | $R_{IN}$                 |                                                        |      | 100      |      | M $\Omega$                   |
| OUTPUT CHARACTERISTICS                 |                          |                                                        |      |          |      |                              |
| Output Voltage High                    | $V_{OH}$                 | $I_L = 1$ mA                                           | +4.1 |          |      | V                            |
|                                        |                          | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$         | +4   |          |      | V                            |
| Output Voltage Low                     | $V_{OL}$                 | $I_L = 1$ mA                                           |      |          | -3.5 | V                            |
|                                        |                          | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$         |      |          | -3.2 | V                            |
| Output Current                         | $I_{OUT}$                | $V_{DROPOUT} < 1.6$ V                                  |      | $\pm 10$ |      | mA                           |
| Short-Circuit Current                  | $I_{SC}$                 | $T_A = 25^\circ\text{C}$                               |      | 22       |      | mA                           |
| Closed-Loop Output Impedance           | $Z_{OUT}$                | $f = 1$ kHz, $A_V = +1$                                |      | 0.05     |      | $\Omega$                     |
| POWER SUPPLY                           |                          |                                                        |      |          |      |                              |
| Power Supply Rejection Ratio           | PSRR                     | $V_S = \pm 2.5$ V to $\pm 18$ V                        | 123  | 128      |      | dB                           |
|                                        |                          | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$         | 120  |          |      | dB                           |
| Supply Current per Amplifier           | $I_{SY}$                 | $V_O = 0$ V                                            |      | 400      | 450  | $\mu\text{A}$                |
|                                        |                          | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$         |      |          | 650  | $\mu\text{A}$                |
| DYNAMIC PERFORMANCE                    |                          |                                                        |      |          |      |                              |
| Slew Rate                              | SR                       | $R_L = 2$ k $\Omega$                                   |      | 1        |      | V/ $\mu\text{s}$             |
| Settling Time to 0.1%                  | $t_s$                    | $V_{IN} = 1$ V step, $R_L = 4$ k $\Omega$ , $A_V = -1$ |      | 2        |      | $\mu\text{s}$                |
| Gain Bandwidth Product                 | GBP                      | $A_V = +1$                                             |      | 4.0      |      | MHz                          |
| NOISE PERFORMANCE                      |                          |                                                        |      |          |      |                              |
| Voltage Noise                          | $e_n$ p-p                | 0.1 Hz to 10 Hz                                        |      | 0.25     |      | $\mu\text{V}$ p-p            |
| Voltage Noise Density                  | $e_n$                    | $f = 1$ Hz                                             |      | 13       |      | nV/ $\sqrt{\text{Hz}}$       |
|                                        |                          | $f = 100$ Hz                                           |      | 7        |      | nV/ $\sqrt{\text{Hz}}$       |
| Current Noise Density                  | $i_n$                    | $f = 1$ kHz                                            |      | 3        |      | pA/ $\sqrt{\text{Hz}}$       |
| MULTIPLE AMPLIFIERS CHANNEL SEPARATION | $C_S$                    | $f = 1$ kHz                                            |      | -120     |      | dB                           |

**ELECTRICAL CHARACTERISTICS,  $\pm 15.0$  V**

$V_{SY} = \pm 15$  V,  $V_{CM} = 0$  V,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

Table 3.

| Parameter                              | Symbol                   | Test Conditions/Comments                                                                              | Min   | Typ      | Max   | Unit                         |
|----------------------------------------|--------------------------|-------------------------------------------------------------------------------------------------------|-------|----------|-------|------------------------------|
| <b>INPUT CHARACTERISTICS</b>           |                          |                                                                                                       |       |          |       |                              |
| Offset Voltage (B Grade, SOIC)         | $V_{OS}$                 | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                        |       | 10       | 35    | $\mu\text{V}$                |
| Offset Voltage Drift (B Grade, SOIC)   | $\Delta V_{OS}/\Delta T$ | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                        |       | 0.1      | 65    | $\mu\text{V}/^\circ\text{C}$ |
| Offset Voltage (A Grade)<br>SOIC       | $V_{OS}$                 | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                        |       | 15       | 50    | $\mu\text{V}$                |
| MSOP                                   |                          |                                                                                                       |       |          | 105   | $\mu\text{V}$                |
| Offset Voltage Drift (A Grade)<br>SOIC | $\Delta V_{OS}/\Delta T$ | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                        |       | 0.2      | 0.55  | $\mu\text{V}/^\circ\text{C}$ |
| MSOP                                   |                          |                                                                                                       |       | 0.5      | 1.2   | $\mu\text{V}/^\circ\text{C}$ |
| Input Bias Current                     | $I_B$                    | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                        | -1    | -0.4     | +1    | nA                           |
| Input Offset Current                   | $I_{OS}$                 | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                        | -1.5  |          | +1.5  | nA                           |
| Input Voltage Range                    |                          |                                                                                                       | -0.5  | +0.1     | +0.5  | nA                           |
| Common-Mode Rejection Ratio            | CMRR                     | $V_{CM} = -13.8$ V to $+13$ V<br>$-40^\circ\text{C} < T_A < +125^\circ\text{C}$                       | -1.0  |          | +1.0  | nA                           |
| Large Signal Voltage Gain              | $A_{VO}$                 | $R_L = 2$ k $\Omega$ , $V_O = -13.0$ V to $+13.0$ V<br>$-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | -13.8 |          | +13   | V                            |
| Input Capacitance                      | $C_{INDM}$<br>$C_{INCM}$ | Differential mode<br>Common mode                                                                      |       | 3        |       | pF                           |
| Input Resistance                       | $R_{IN}$                 |                                                                                                       |       | 5        |       | pF                           |
| <b>OUTPUT CHARACTERISTICS</b>          |                          |                                                                                                       |       |          |       |                              |
| Output Voltage High                    | $V_{OH}$                 | $I_L = 1$ mA<br>$-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                        | +14.1 |          |       | V                            |
| Output Voltage Low                     | $V_{OL}$                 | $I_L = 1$ mA<br>$-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                        | +14   |          | -13.5 | V                            |
| Output Current                         | $I_{OUT}$                | $V_{DROPOUT} < 1.2$ V                                                                                 |       | $\pm 10$ | -13.2 | V                            |
| Short-Circuit Current                  | $I_{SC}$                 | $T_A = 25^\circ\text{C}$                                                                              |       | 22       |       | mA                           |
| Closed-Loop Output Impedance           | $Z_{OUT}$                | $f = 1$ kHz, $A_V = +1$                                                                               |       | 0.05     |       | $\Omega$                     |
| <b>POWER SUPPLY</b>                    |                          |                                                                                                       |       |          |       |                              |
| Power Supply Rejection Ratio           | PSRR                     | $V_S = \pm 2.5$ V to $\pm 18$ V<br>$-40^\circ\text{C} < T_A < +125^\circ\text{C}$                     | 123   | 128      |       | dB                           |
| Supply Current per Amplifier           | $I_{SY}$                 | $V_O = 0$ V<br>$-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                         | 120   | 400      | 500   | dB                           |
| <b>DYNAMIC PERFORMANCE</b>             |                          |                                                                                                       |       |          |       |                              |
| Slew Rate                              | SR                       | $R_L = 2$ k $\Omega$                                                                                  |       | 1        |       | $\text{V}/\mu\text{s}$       |
| Settling Time to 0.01%                 | $t_s$                    | $V_{IN} = 10$ V p-p, $R_L = 4$ k $\Omega$ , $A_V = -1$                                                |       | 9        |       | $\mu\text{s}$                |
| Settling Time to 0.1%                  | $t_s$                    | $V_{IN} = 10$ V p-p, $R_L = 4$ k $\Omega$ , $A_V = -1$                                                |       | 8        |       | $\mu\text{s}$                |
| Gain Bandwidth Product                 | GBP                      | $A_V = +1$                                                                                            |       | 3.9      |       | MHz                          |
| <b>NOISE PERFORMANCE</b>               |                          |                                                                                                       |       |          |       |                              |
| Voltage Noise                          | $e_n$ p-p                | 0.1 Hz to 10 Hz                                                                                       |       | 0.25     |       | $\mu\text{V}$ p-p            |
| Voltage Noise Density                  | $e_n$                    | $f = 1$ Hz                                                                                            |       | 13       |       | nV/ $\sqrt{\text{Hz}}$       |
|                                        |                          | $f = 100$ Hz                                                                                          |       | 7        |       | nV/ $\sqrt{\text{Hz}}$       |
| Current Noise Density                  | $i_n$                    | $f = 1$ kHz                                                                                           |       | 3        |       | pA/ $\sqrt{\text{Hz}}$       |
| MULTIPLE AMPLIFIERS CHANNEL SEPARATION | $C_S$                    | $f = 1$ kHz                                                                                           |       | -120     |       | dB                           |

**ABSOLUTE MAXIMUM RATINGS**

Table 4.

| Parameter                            | Rating          |
|--------------------------------------|-----------------|
| Supply Voltage                       | 36 V            |
| Input Voltage                        | $\pm V_{SY}$    |
| Differential Input Voltage           | $\pm V_{SY}$    |
| Storage Temperature Range            |                 |
| MSOP and SOIC_N Packages             | –65°C to +150°C |
| Operating Temperature Range          | –40°C to +125°C |
| Junction Temperature Range           |                 |
| R and RM Packages                    | –65°C to +150°C |
| Lead Temperature, Soldering (10 sec) | 300°C           |

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**THERMAL RESISTANCE**

$\theta_{JA}$  is specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages.

Table 5. Thermal Resistance

| Package Type  | $\theta_{JA}$ | $\theta_{JC}$ | Unit |
|---------------|---------------|---------------|------|
| 8-Lead MSOP   | 190           | 44            | °C/W |
| 8-Lead SOIC_N | 158           | 43            | °C/W |

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

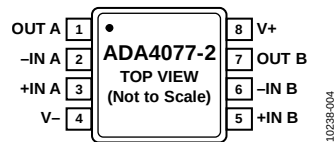


Figure 4. Pin Configuration, 8-Lead MSOP (RM Suffix)

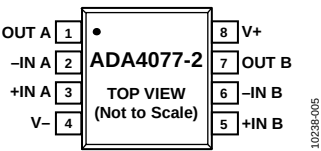


Figure 5. Pin Configuration, 8-Lead SOIC\_N (R Suffix)

Table 6. ADA4077-2 Pin Function Descriptions, MSOP and SOIC

| Pin No. | Mnemonic | Description                    |
|---------|----------|--------------------------------|
| 1       | OUT A    | Output, Channel A.             |
| 2       | –IN A    | Inverting Input, Channel A.    |
| 3       | +IN A    | Noninverting Input, Channel A. |
| 4       | V–       | Negative Supply Voltage.       |
| 5       | +IN B    | Noninverting Input, Channel B. |
| 6       | –IN B    | Inverting Input, Channel B.    |
| 7       | OUT B    | Output, Channel B.             |
| 8       | V+       | Positive Supply Voltage.       |

## TYPICAL PERFORMANCE CHARACTERISTICS

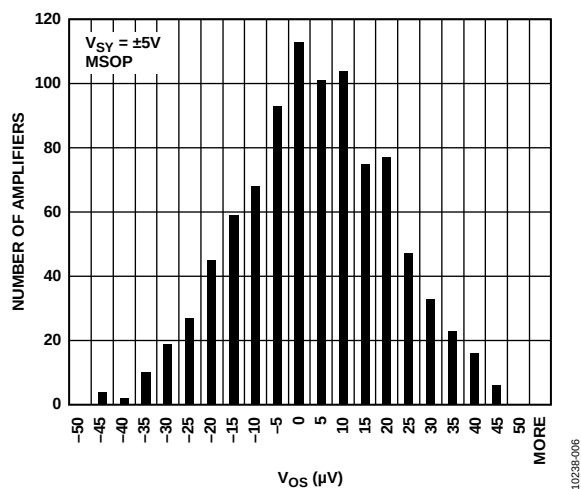


Figure 6. Offset Voltage Distribution

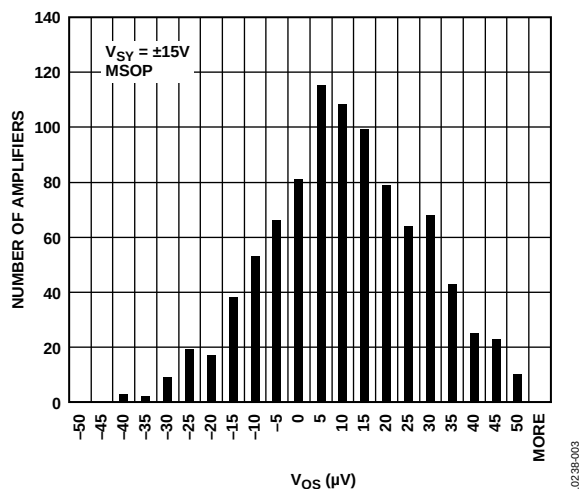


Figure 9. Offset Voltage Distribution

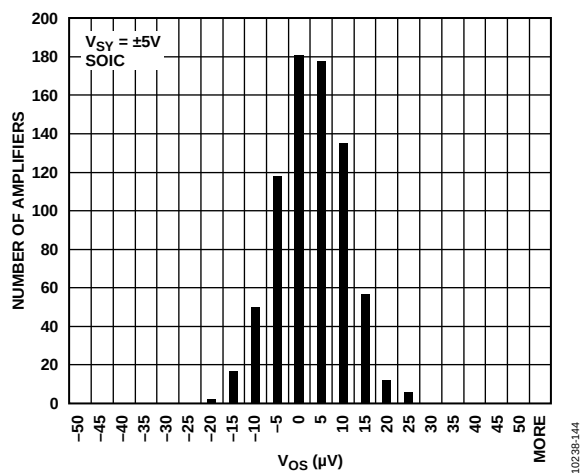


Figure 7. Offset Voltage Distribution

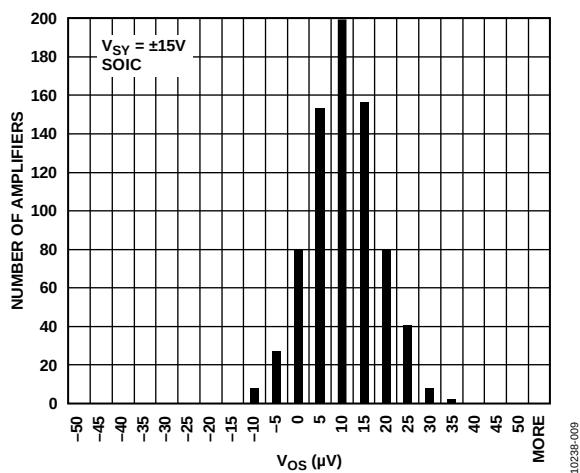


Figure 10. Offset Voltage Distribution

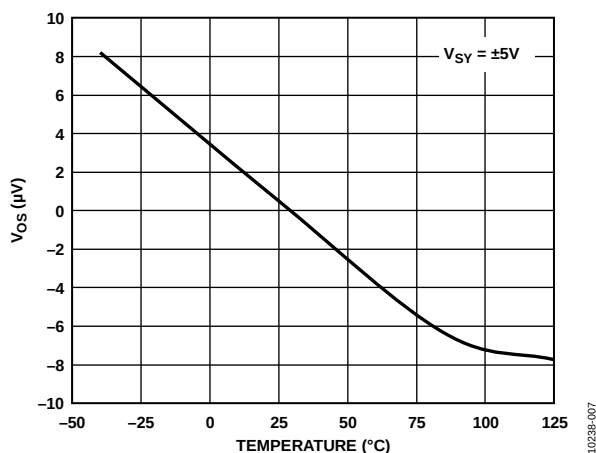


Figure 8. Offset Voltage vs. Temperature

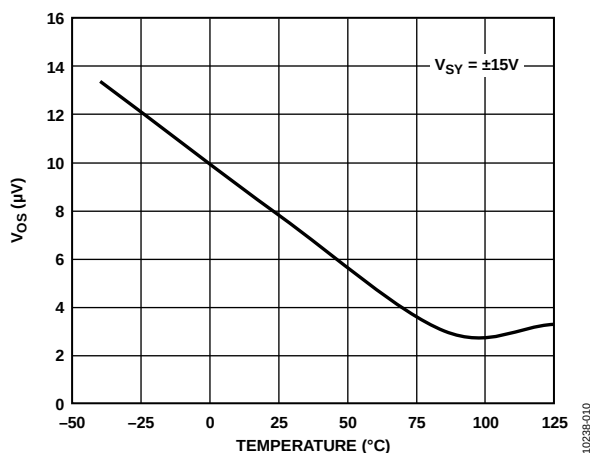


Figure 11. Offset Voltage vs. Temperature

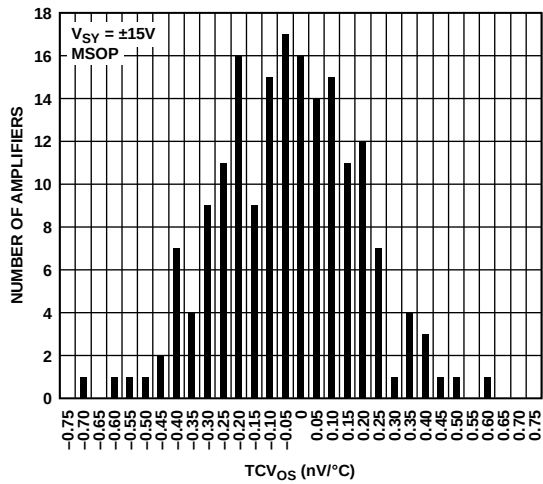


Figure 12. TCV<sub>OS</sub>, MSOP

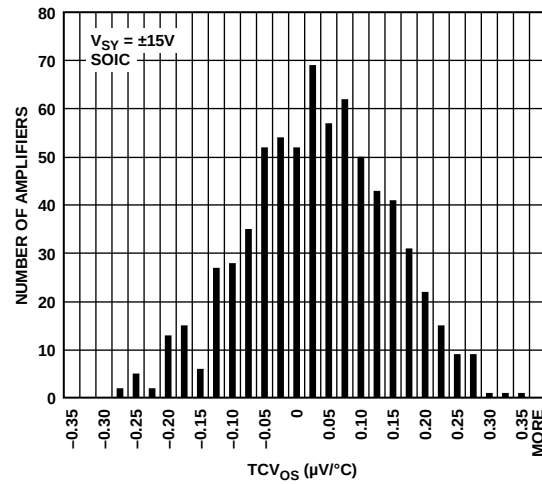


Figure 15. TCV<sub>OS</sub>, SOIC

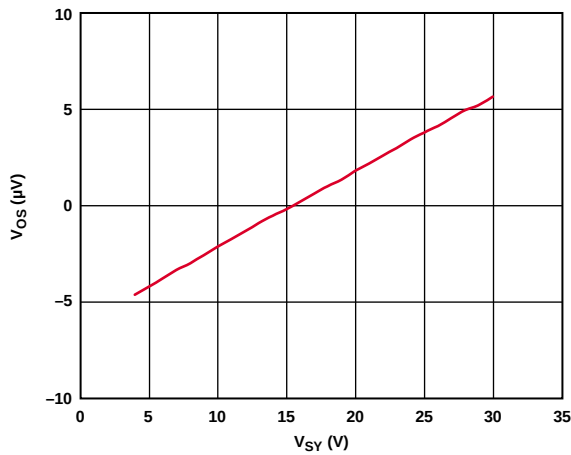


Figure 13.  $V_{OS}$  vs. Supplies

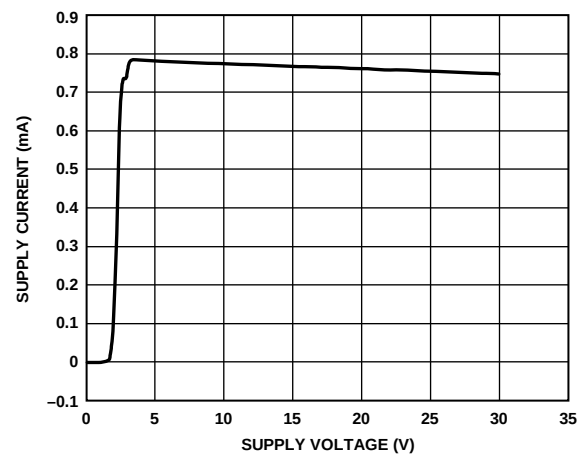


Figure 16.  $I_{SY}$  vs.  $V_{SY}$

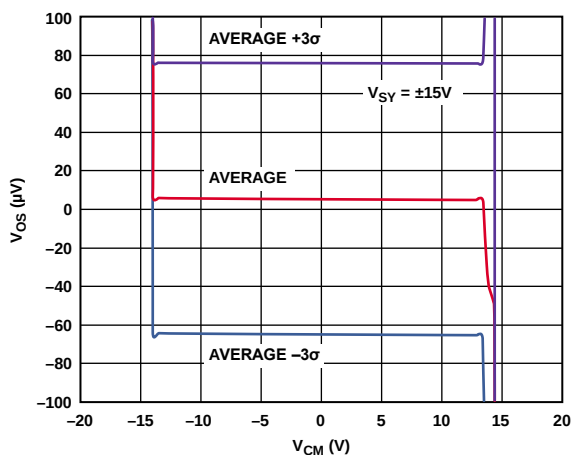


Figure 14.  $V_{OS}$  vs.  $V_{CM}$

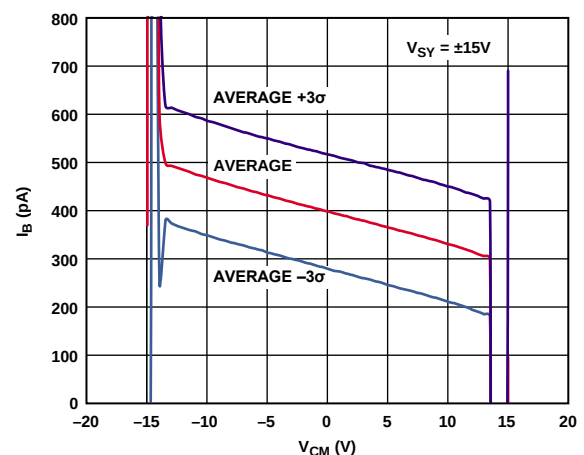


Figure 17. Input Bias Current vs.  $V_{CM}$

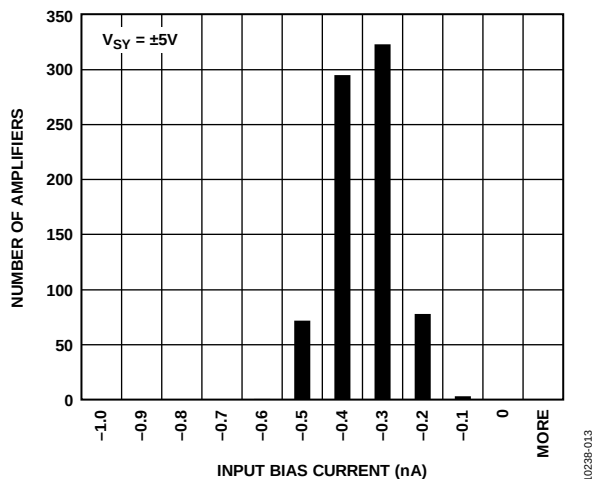


Figure 18. Input Bias Current

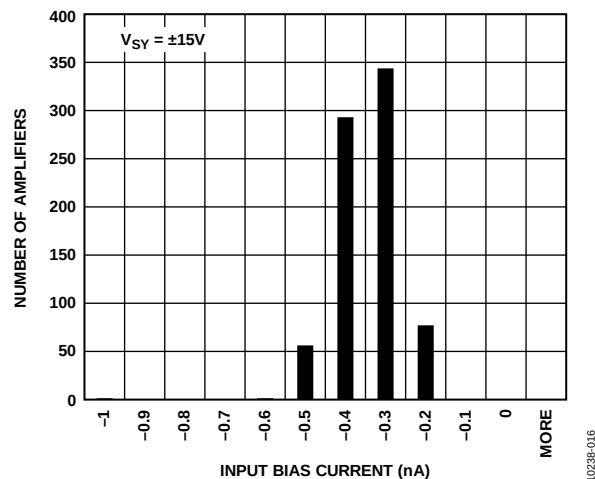


Figure 21. Input Bias Current

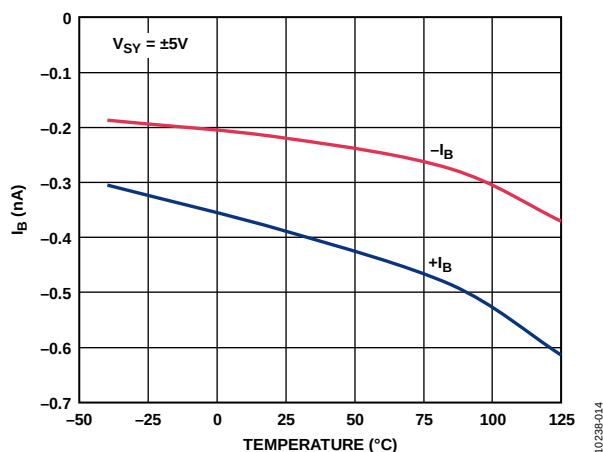


Figure 19. Input Bias Current vs. Temperature

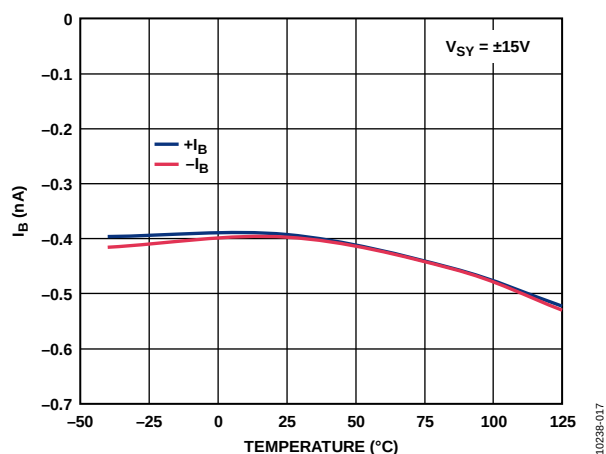
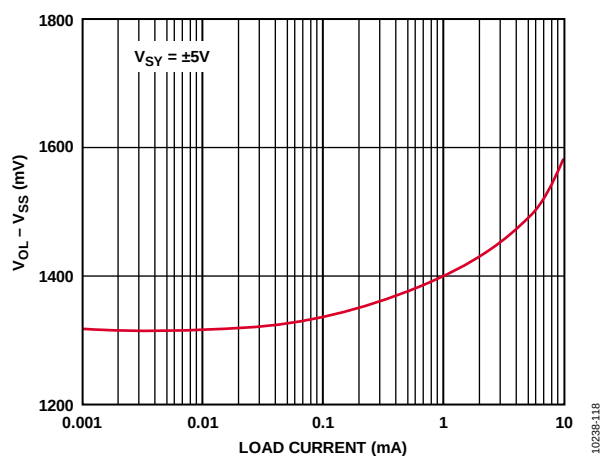
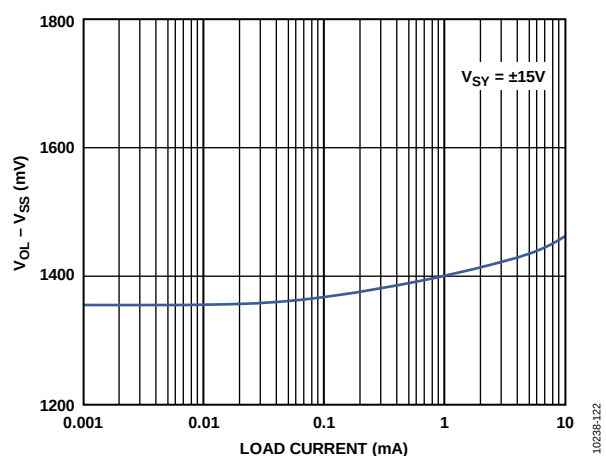


Figure 22. Input Bias Current vs. Temperature

Figure 20.  $V_{OL}$  vs. LoadFigure 23.  $V_{OL}$  vs. Load

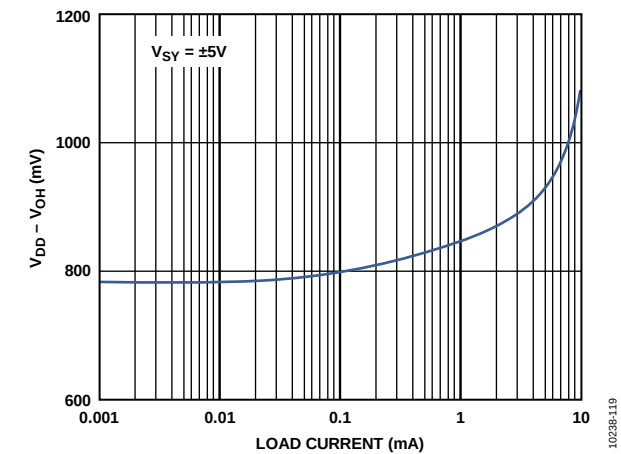


Figure 24. Output Dropout Voltage vs. Load

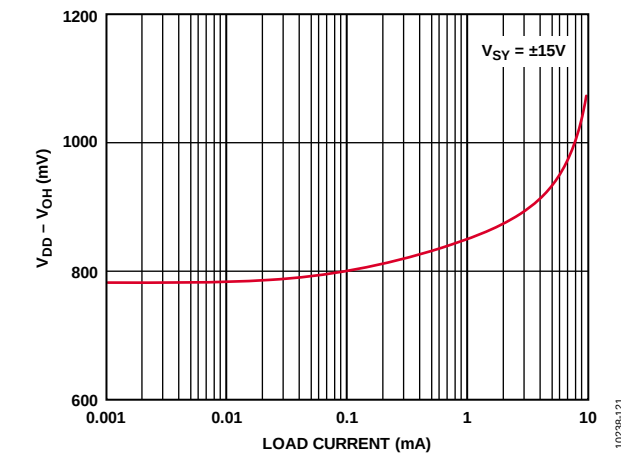


Figure 27. Output Dropout Voltage vs. Load

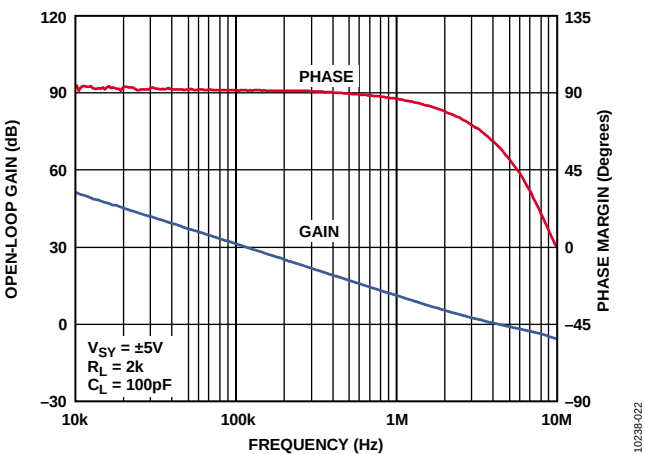


Figure 25. Open-Loop Gain and Phase vs. Frequency

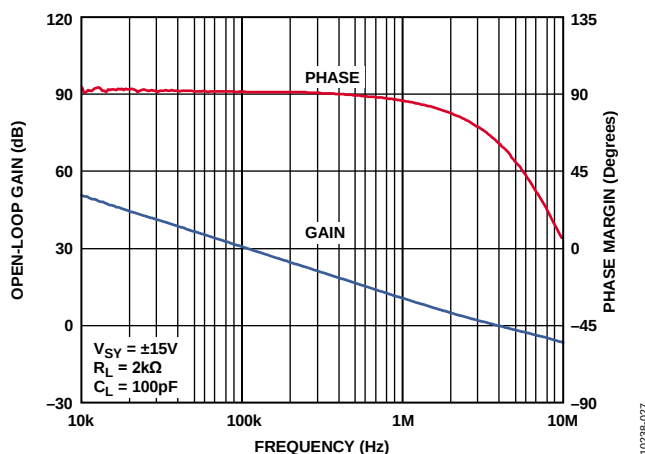


Figure 28. Open-Loop Gain and Phase vs. Frequency

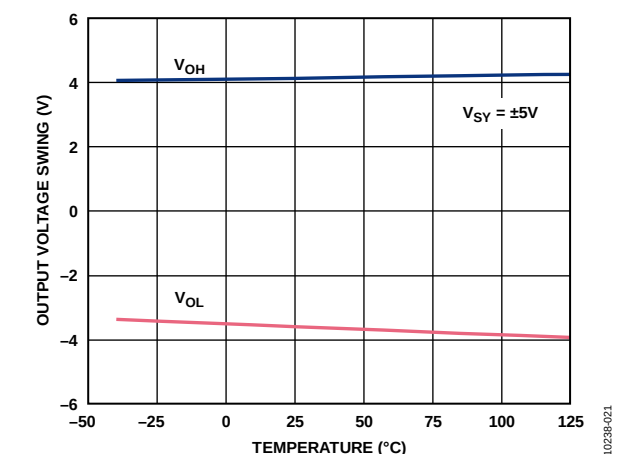


Figure 26. Output Voltage Swing vs. Temperature

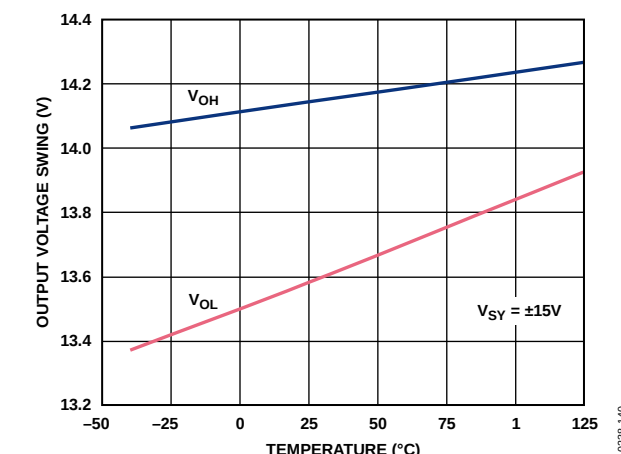
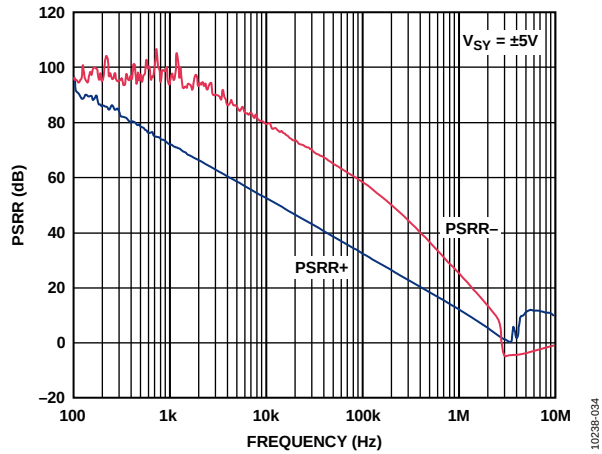
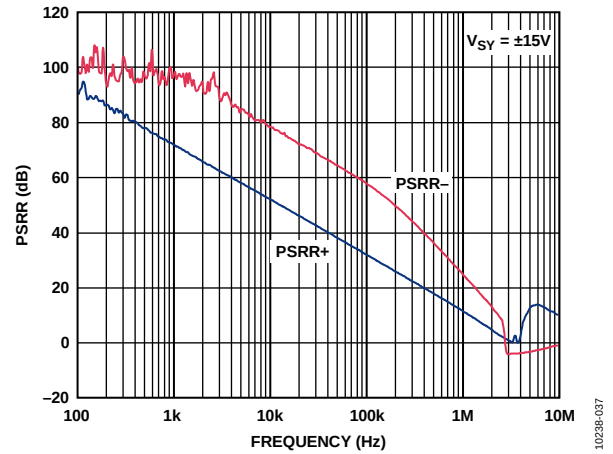


Figure 29. Output Voltage Swing vs. Temperature

Figure 30. PSRR vs. Frequency,  $\pm 5\text{ V}$ 

1023B-034

Figure 33. PSRR vs. Frequency,  $\pm 15\text{ V}$ 

1023B-037

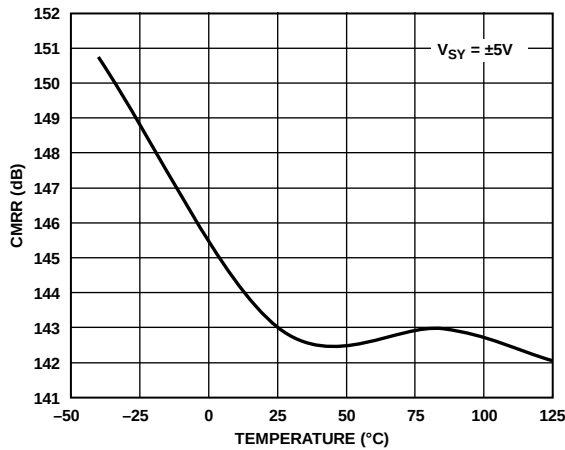


Figure 31. CMRR vs. Temperature

1023B-030

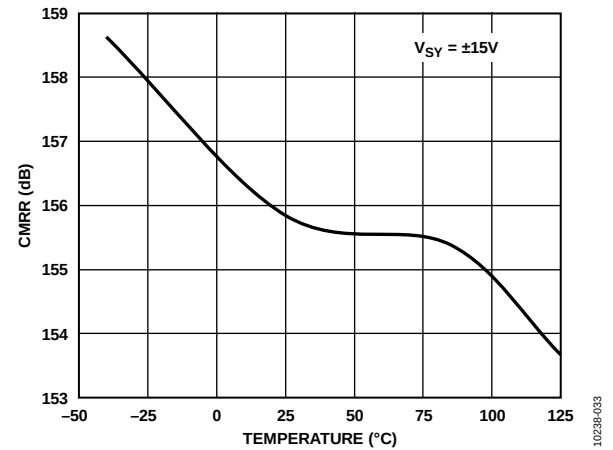


Figure 34. CMRR vs. Temperature

1023B-033

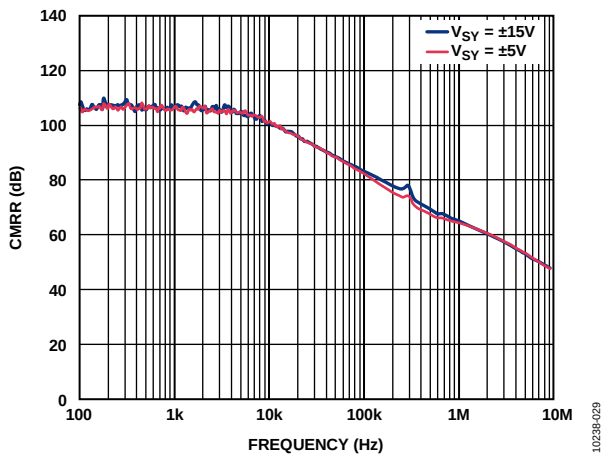


Figure 32. CMRR vs. Frequency

1023B-029

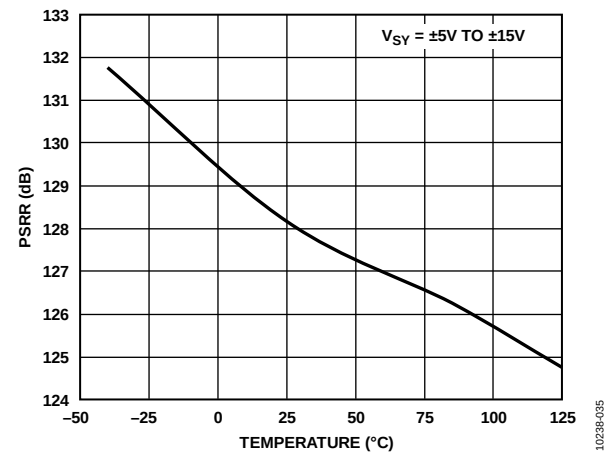


Figure 35. PSRR vs. Temperature

1023B-035

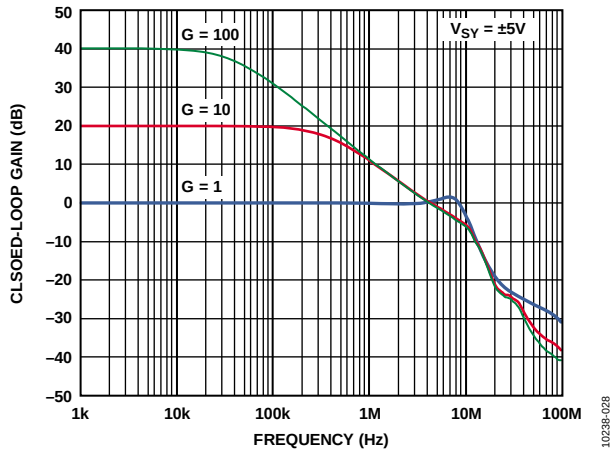


Figure 36. Closed-Loop Gain vs. Frequency

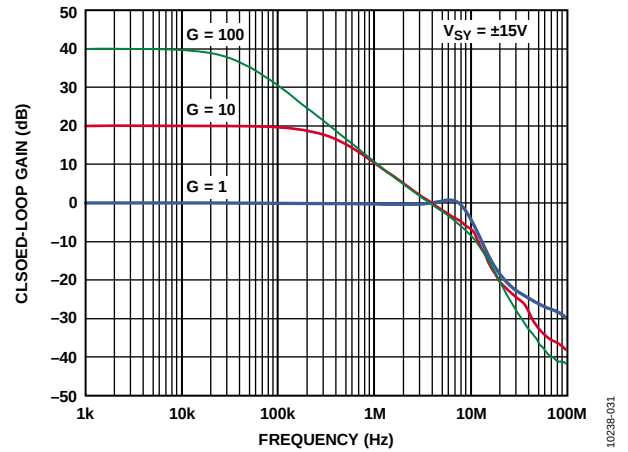


Figure 39. Closed-Loop Gain vs. Frequency

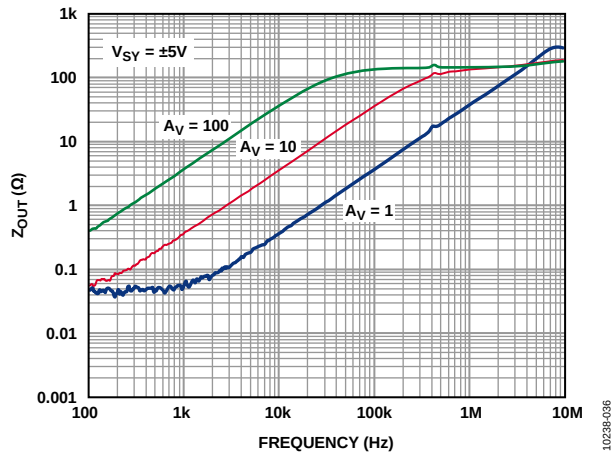


Figure 37. Output Impedance vs. Frequency

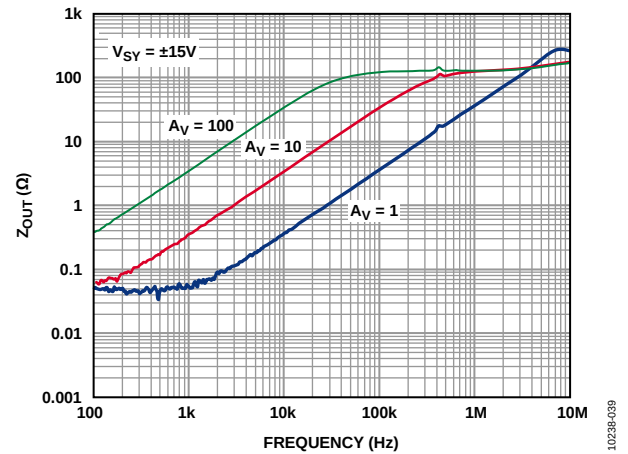


Figure 40. Output Impedance vs. Frequency

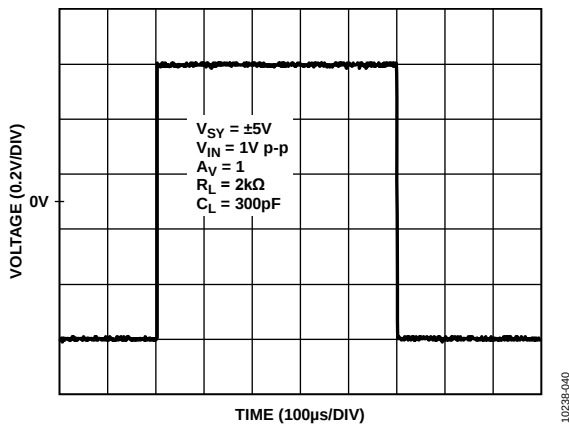


Figure 38. Large Signal Transient Response

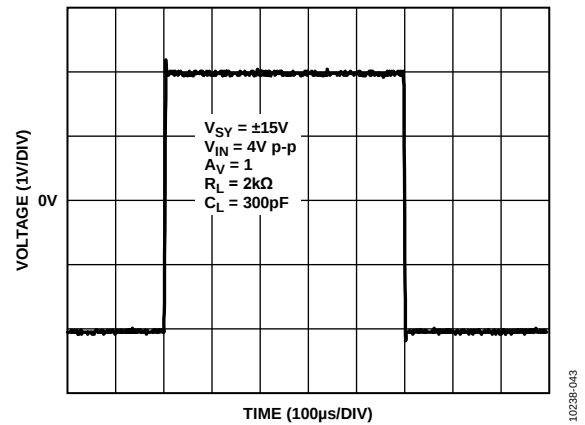


Figure 41. Large Signal Transient Response

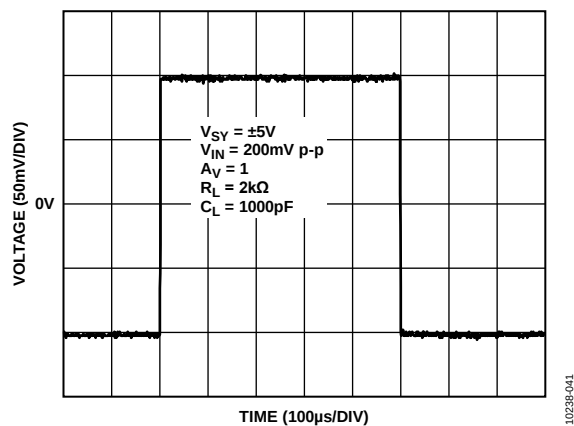


Figure 42. Small Signal Transient Response

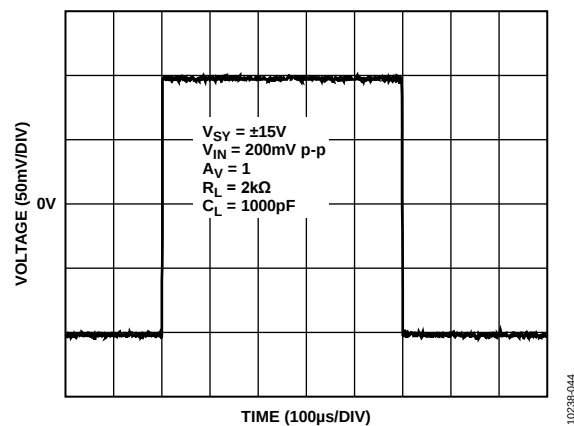


Figure 45. Small Signal Transient Response

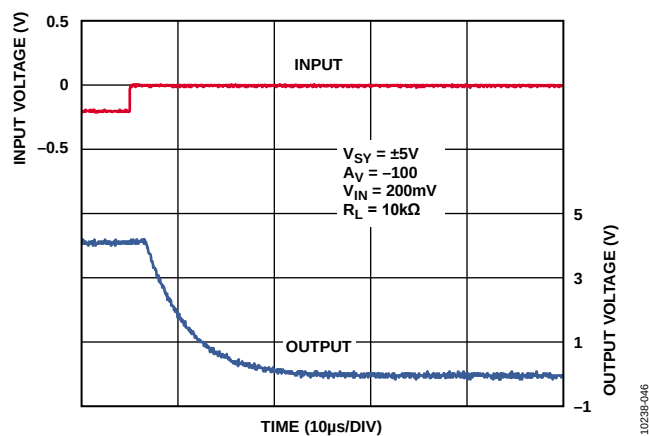


Figure 43. Positive Overload Recovery

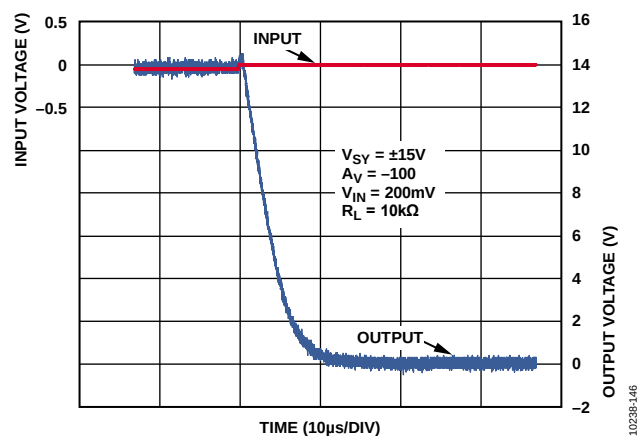


Figure 46. Positive Overload Recovery

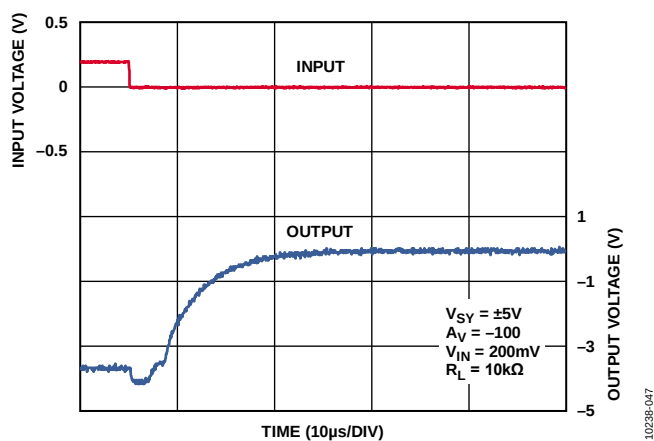


Figure 44. Negative Overload Recovery

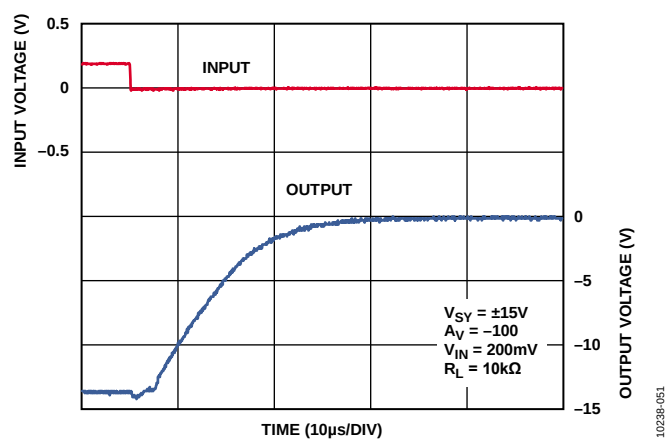


Figure 47. Negative Overload Recovery

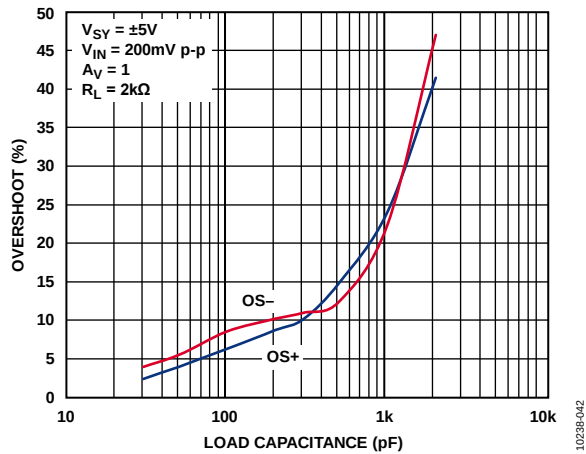


Figure 48. Small Signal Overshoot vs. Load Capacitance

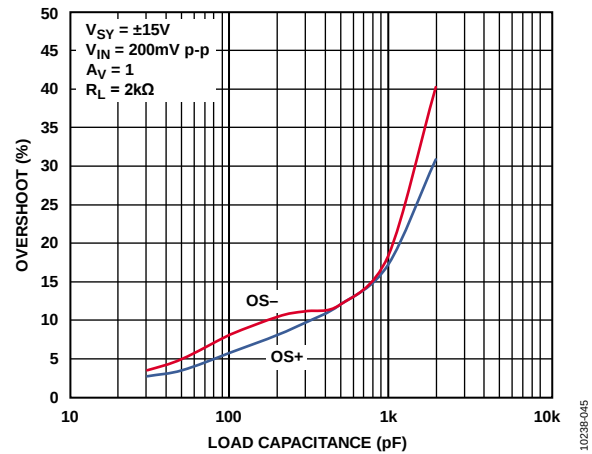


Figure 51. Small Signal Overshoot vs. Load Capacitance

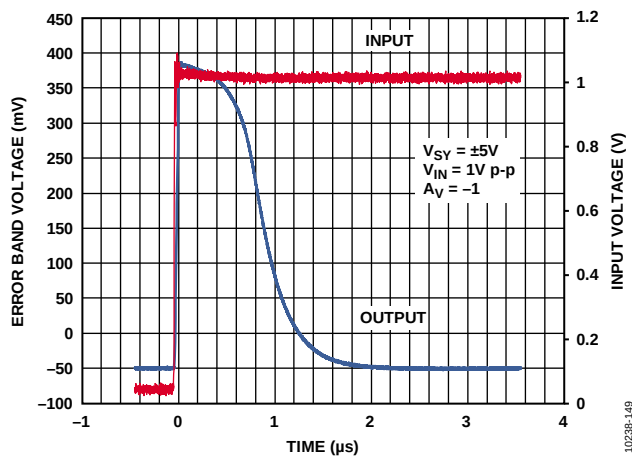


Figure 49. Positive Settling Time

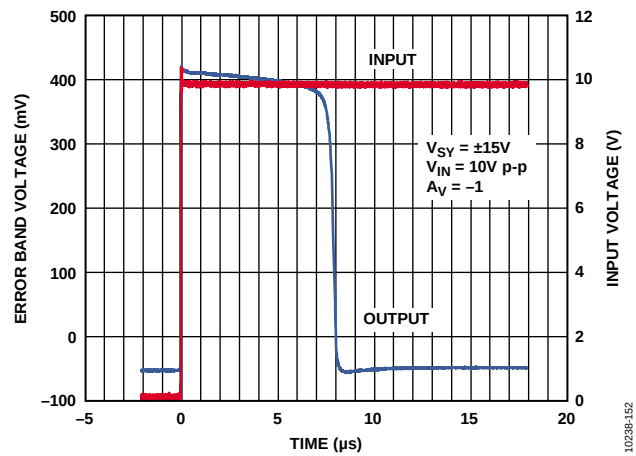


Figure 52. Positive Settling Time

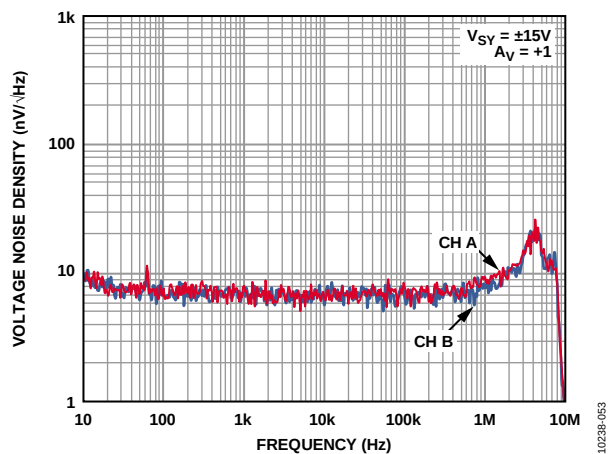


Figure 50. Voltage Noise Density vs. Frequency

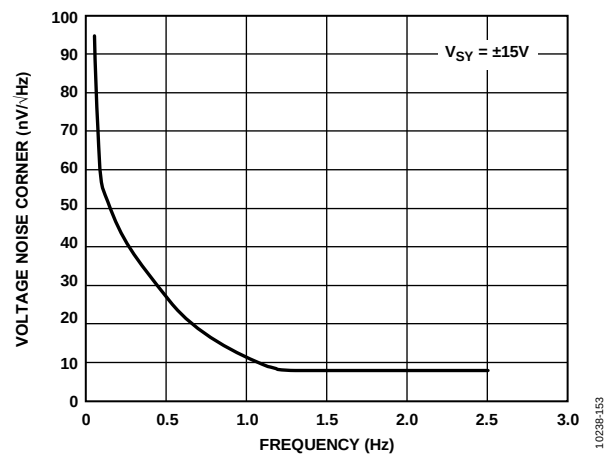


Figure 53. Voltage Noise Corner Frequency

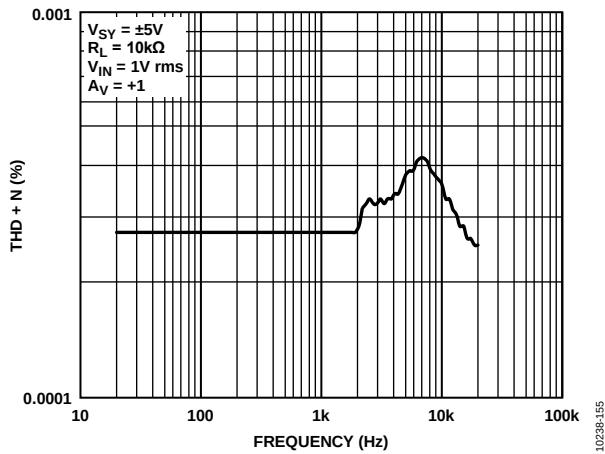


Figure 54. THD + N vs. Frequency

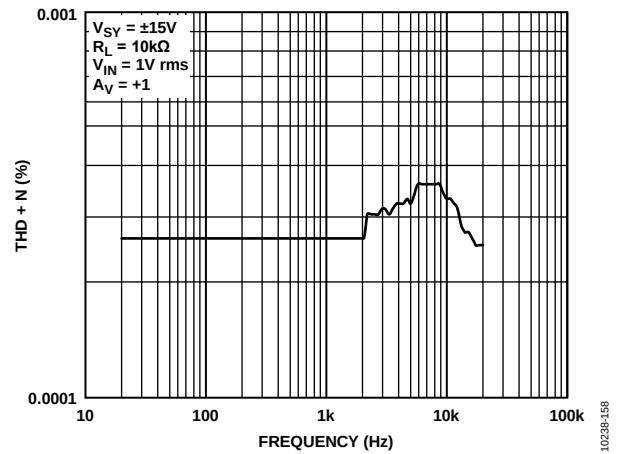


Figure 56. THD + N vs. Frequency

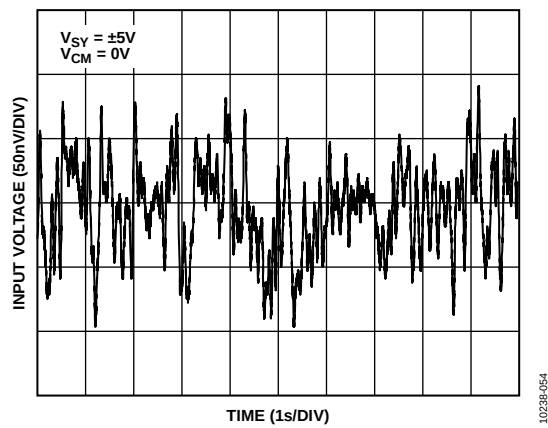


Figure 55. 0.1 Hz to 10 Hz Noise

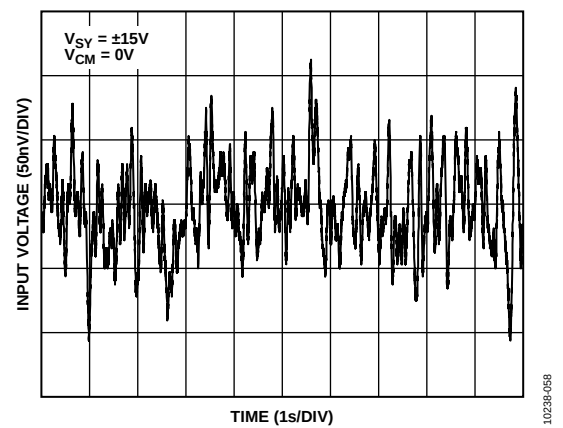


Figure 57. 0.1 Hz to 10 Hz Noise

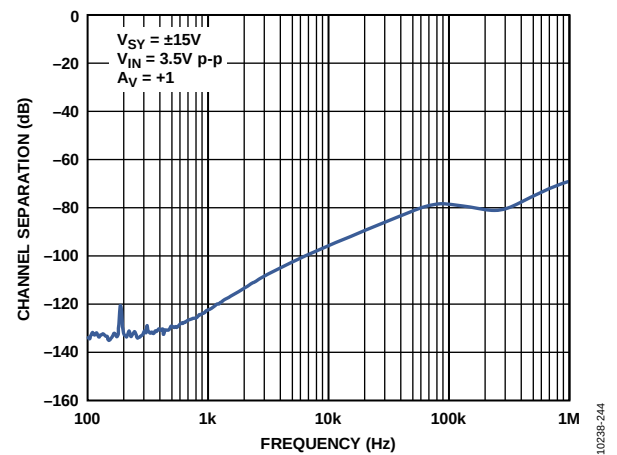


Figure 58. Channel Separation

## THEORY OF OPERATION

The [ADA4077-2](#) is the sixth generation of the Analog Devices, Inc., industry-standard [OP07](#) amplifier family. The [ADA4077-2](#) is a high precision, low noise operational amplifier with a combination of extremely low offset voltage and very low input bias currents. Unlike JFET amplifiers, the low bias and offset currents are relatively insensitive to ambient temperatures, even up to 125°C.

The Analog Devices proprietary process technology and linear design expertise have produced a high voltage amplifier with superior performance to the [OP07](#), [OP77](#), [OP177](#), and [OP1177](#) in tiny, 8-lead SOIC and 8-lead MSOP packages. Despite its small size, the [ADA4077-2](#) offers numerous improvements, including low wideband noise, wide bandwidth, lower offset and offset drift, lower input bias current, and complete freedom from phase inversion.

The [ADA4077-2](#) has a specified operating temperature range of –40°C to +125°C with a MSL1 rating, which is as wide as any similar device in a plastic surface-mount package. This is increasingly important as PCB and overall system sizes continue to shrink, causing internal system temperatures to rise.

In the [ADA4077-2](#), power consumption is reduced by a factor of four from the [OP177](#), and bandwidth and slew rate have both increased by a factor of six. The low power dissipation and very stable performance vs. temperature also act to reduce warm-up drift errors to insignificant levels.

Inputs are protected internally from overvoltage conditions referenced to either supply rail. Like any high performance amplifier, maximum performance is achieved by following appropriate circuit and PCB guidelines.

## APPLICATIONS INFORMATION

### OUTPUT PHASE REVERSAL

Phase reversal is defined as a change of polarity in the amplifier transfer function. Many operational amplifiers exhibit phase reversal when the voltage applied to the input is greater than the maximum common-mode voltage. In some instances, this can cause permanent damage to the amplifier. In feedback loops, it can result in system lockups or equipment damage. The [ADA4077-2](#) is immune to phase reversal problems even at input voltages beyond the supplies.

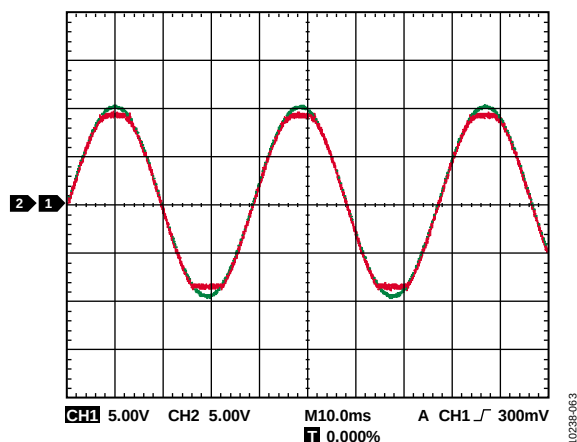


Figure 59. No Phase Reversal

### LOW POWER LINEARIZED RTD

A common application for a single element varying bridge is an RTD thermometer amplifier, as shown in Figure 60. The excitation is delivered to the bridge by a 2.5 V reference applied at the top of the bridge.

RTDs can have a thermal resistance as high as 0.5°C to 0.8°C per mW. To minimize errors due to resistor drift, the current through each leg of the bridge must be kept low. In this circuit, the amplifier supply current flows through the bridge. However, at the [ADA4077-2](#) maximum supply current of 500  $\mu$ A, the RTD dissipates less than 0.1 mW of power, even at the highest resistance. Errors due to power dissipation in the bridge are kept under 0.1°C.

Calibration of the bridge is made at the minimum value of the temperature to be measured by adjusting RP until the output is zero.

To calibrate the output span, set the full-scale and linearity potentiometers to midpoint and apply a 500°C temperature to the sensor or substitute the equivalent 500°C RTD resistance.

Adjust the full-scale potentiometer for a 5 V output. Finally, apply 250°C or the equivalent RTD resistance and adjust the linearity potentiometer for 2.5 V output. The circuit achieves better than  $\pm 0.5^\circ\text{C}$  accuracy after adjustment.

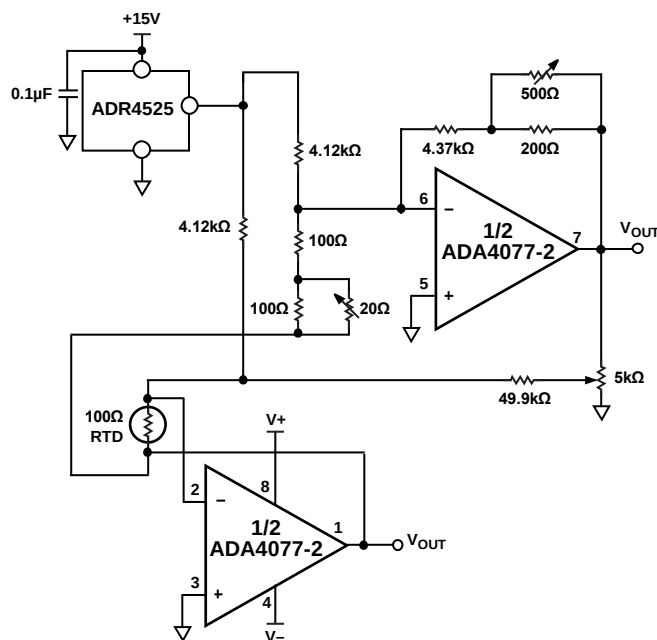


Figure 60. Low Power Linearized RTD Circuit

**PROPER BOARD LAYOUT**

The [ADA4077-2](#) is a high precision device. To ensure optimum performance at the PCB level, care must be taken in the design of the board layout.

To avoid leakage currents, maintain a clean and moisture-free board surface. Coating the surface creates a barrier to moisture accumulation and helps reduce parasitic resistance on the board.

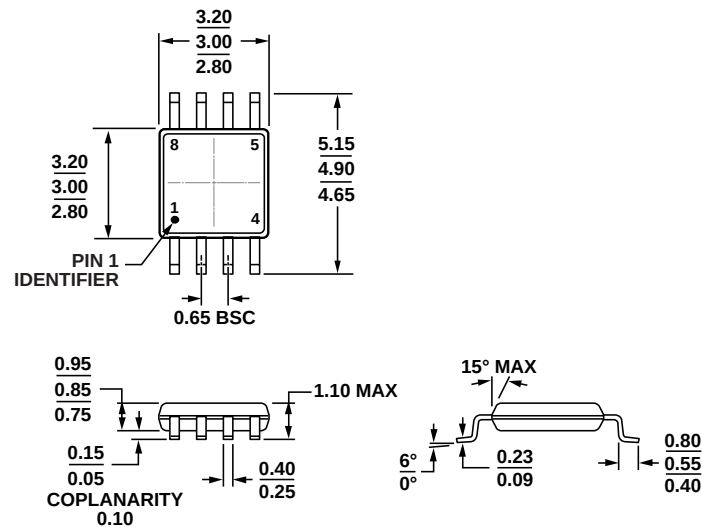
Keeping supply traces short and properly bypassing the power supplies minimizes power supply disturbances caused by output current variation, such as when driving an ac signal into a heavy load. Connect bypass capacitors as closely as possible to the device supply pins. Stray capacitances are a concern at the outputs and the inputs of the amplifier. It is recommended that signal traces be kept at least 5 mm from supply lines to minimize coupling.

A variation in temperature across the PCB can cause a mismatch in the Seebeck voltages at solder joints and other points where dissimilar metals are in contact, resulting in thermal voltage errors. To minimize these thermocouple effects, orient resistors so heat sources warm both ends equally. Input signal paths should contain matching numbers and types of components, where possible, to match the number and type of thermocouple junctions. For example, dummy components such as zero value resistors can be used to match real resistors in the opposite input path. Place matching components in close proximity to each other and orient them in the same manner. Ensure that leads are of equal length so that thermal conduction is in equilibrium. Keep heat sources on the PCB as far away from amplifier input circuitry as is practical.

The use of a ground plane is highly recommended. A ground plane reduces EMI noise and helps to maintain a constant temperature across the circuit board.

# PACKAGING AND ORDERING INFORMATION

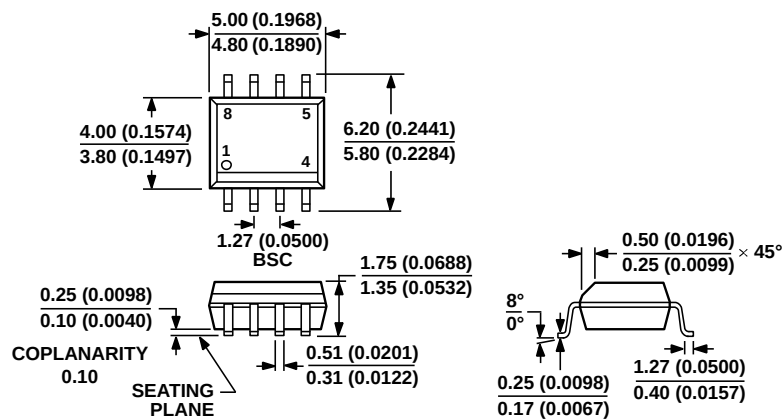
## OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-187-AA

Figure 61. 8-Lead Mini Small Outline Package [MSOP]  
(RM-8)

Dimensions shown in millimeters



COMPLIANT TO JEDEC STANDARDS MS-012-AA

CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS  
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR  
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 62. 8-Lead Standard Small Outline Package [SOIC\_N]  
Narrow Body  
(R-8)

Dimensions shown in millimeters and (inches)

## ORDERING GUIDE

| Model <sup>1</sup> | Temperature Range | Package Description                            | Package Option | Branding |
|--------------------|-------------------|------------------------------------------------|----------------|----------|
| ADA4077-2-ARMZ     | –40°C to +125°C   | 8-Lead Mini Small Outline Package [MSOP]       | RM-8           | A2X      |
| ADA4077-2ARMZ-R7   | –40°C to +125°C   | 8-Lead Mini Small Outline Package [MSOP]       | RM-8           | A2X      |
| ADA4077-2ARMZ-RL   | –40°C to +125°C   | 8-Lead Mini Small Outline Package [MSOP]       | RM-8           | A2X      |
| ADA4077-2ARZ       | –40°C to +125°C   | 8-Lead Standard Small Outline Package [SOIC_N] | R-8            |          |
| ADA4077-2ARZ-R7    | –40°C to +125°C   | 8-Lead Standard Small Outline Package [SOIC_N] | R-8            |          |
| ADA4077-2ARZ-RL    | –40°C to +125°C   | 8-Lead Standard Small Outline Package [SOIC_N] | R-8            |          |
| ADA4077-2BRZ       | –40°C to +125°C   | 8-Lead Standard Small Outline Package [SOIC_N] | R-8            |          |
| ADA4077-2BRZ-R7    | –40°C to +125°C   | 8-Lead Standard Small Outline Package [SOIC_N] | R-8            |          |
| ADA4077-2BRZ-RL    | –40°C to +125°C   | 8-Lead Standard Small Outline Package [SOIC_N] | R-8            |          |

<sup>1</sup> Z = RoHS Compliant Part.

Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

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- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



## JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели,  
кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



Телефон: 8 (812) 309-75-97 (многоканальный)

Факс: 8 (812) 320-03-32

Электронная почта: [ocean@oceanchips.ru](mailto:ocean@oceanchips.ru)

Web: <http://oceanchips.ru/>

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А